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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Standard Recovery Diodes (Stud Version), 70 A



DO-203AB (DO-5)

PRODUCT SUMMARY				
I _{F(AV)}	70 A			
Package	DO-203AB (DO-5)			
Circuit configuration	Single diode			

FEATURES

- High surge current capability
- Designed for a wide range of applications



- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600 V V_{RRM}
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- · Battery charges

MAJOR RATINGS AND CHARACTERISTICS					
DADAMETED	TEST CONDITIONS	70H	LINUTO		
PARAMETER	TEST CONDITIONS	10 TO 120	140/160	UNITS	
1		70	70	А	
I _{F(AV)}	T _C	140	110	°C	
I _{F(RMS)}		110	110	A	
1	50 Hz	1200	1200	^	
IFSM	60 Hz	1250	1250	A	
2t	50 Hz	7100	7100	A ² s	
1-1	60 Hz	6450	6450	A-S	
V _{RRM}	Range	100 to 1200	1400/1600	V	
TJ		-65 to +180	-65 to +150	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE	VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{R(BR)} , MINIMUM AVALANCHE VOLTAGE V	$\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ \text{AT T}_{J} &= \text{T}_{J} \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$	
	10	100	200	200		
	20	200	300	300	15	
30		300	400	400	15	
	40	400	500	500		
\(C 70HE(D)	60	600	720	725		
VS-70HF(R)	80	800	960	950	9	
	100	1000	1200	1150	9	
	120	1200	1440	1350		
	140	1400	1650	1550	4 E	
1	160	1600	1900	1750	4.5	



FORWARD CONDUCTION								
PARAMETER	SYMBOL	OL TEST CONDITIONS		70HF	F(R)	UNITS		
PANAMETEN	STIVIBUL		TEST CON	DITIONS	10 to 120	140/160	UNITS	
Maximum average forward current	I _{F(AV)}	180° condu	ction, half sine	wave	70)	Α	
at case temperature	'F(AV)	100 Condu	ction, nan sine	wave	140	110	°C	
Maximum RMS forward current	I _{F(RMS)}				11	0	Α	
		t = 10 ms	No voltage		1200 1250		A	
Maximum peak, one cycle forward,	1	t = 8.3 ms	reapplied					
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1000			
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	105	50		
	l ² t	t = 10 ms	No voltage		7100		- A ² s	
Maximum I ² t for fusing		t = 8.3 ms	reapplied		6450			
Maximum I-t for fusing	1-1	t = 10 ms	100 % V _{RRM}		5000			
		t = 8.3 ms	reapplied		455	50		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		71 C	00	A²√s		
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.7	'9	V		
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		1.00]		
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum 2.33		3	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 1.53		3	1112.2	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 220 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu \text{s rectangular wave}$ 1.35			1.46	V		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	70H	UNITS	
PANAMETEN	STINIBUL	TEST CONDITIONS	10 to 120	140/160	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65 to +180	-65 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation 0.45		45	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
		Not lubricated thread, tighting on nut (1)	3.4	(30)	
Maximum allowable mounting torque		Lubricated thread, tighting on nut (1)	2.3 (20)		N·m
(+0 %, -10 %)		Not lubricated thread, tighting on hexagon (2)	4.2	(37)	(lbf · in)
		Lubricated thread, tighting on hexagon (2)	3.2	(28)	
Approximate weight			1	7	g
Approximate weight			0	.6	oz.
Case style		See dimensions - link at the end of datasheet	neet DO-203AB (DO-5))

Notes

- (1) Recommended for pass-through holes
- (2) Recommended for holed threaded heatsinks

△R _{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.08	0.06		
120°	0.10	0.11		
90°	0.13	0.14	$T_J = T_J$ maximum	K/W
60°	0.19	0.20		
30°	0.30	0.30		

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

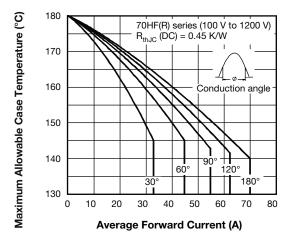


Fig. 1 - Current Ratings Characteristics

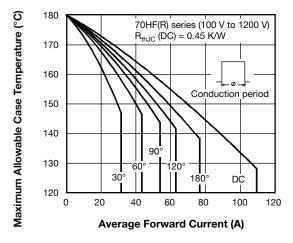


Fig. 2 - Current Ratings Characteristics

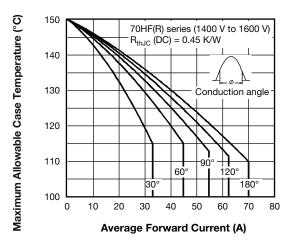


Fig. 3 - Current Ratings Characteristics

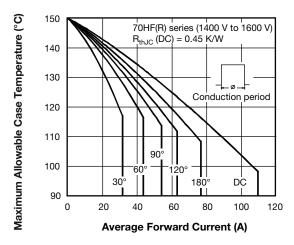


Fig. 4 - Current Ratings Characteristics

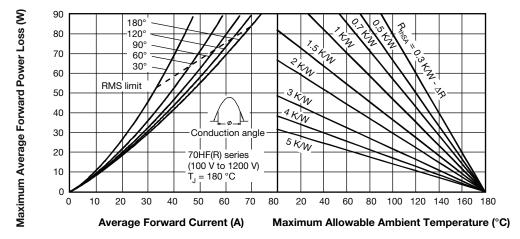


Fig. 5 - Forward Power Loss Characteristics



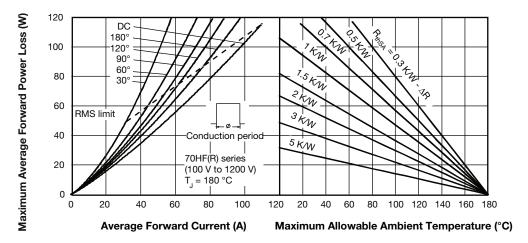


Fig. 6 - Forward Power Loss Characteristics

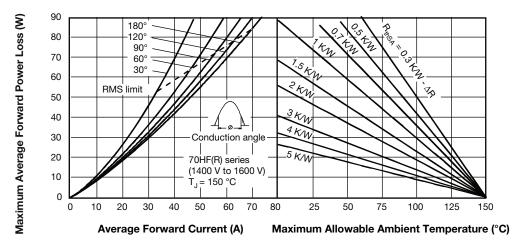


Fig. 7 - Forward Power Loss Characteristics

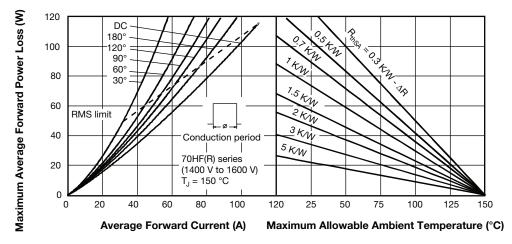


Fig. 8 - Forward Power Loss Characteristics

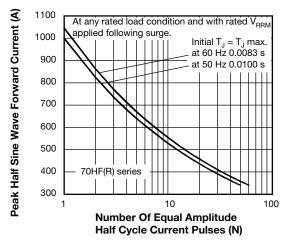


Fig. 9 - Maximum Non-Repetitive Surge Current

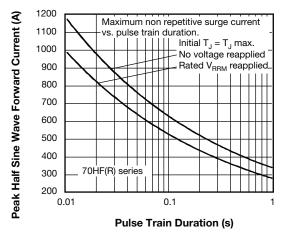


Fig. 10 - Maximum Non-Repetitive Surge Current

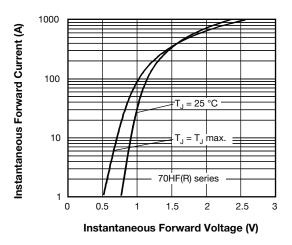


Fig. 11 - Forward Voltage Drop Characteristics

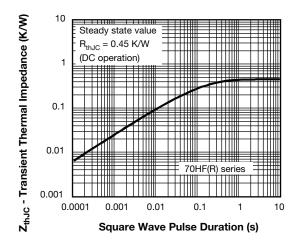


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

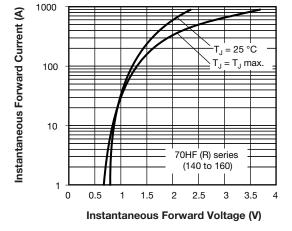
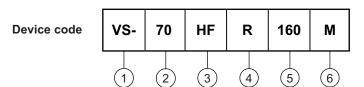


Fig. 13 - Forward Voltage Drop Characteristics



ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - 70 = standard device

71 = not isolated lead

72 = isolated lead with silicone sleeve

(red = reverse polarity)

(blue = normal polarity)

3 - HF = standard diode

None = stud normal polarity (cathode to stud)

• R = stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

- • None = stud base DO-203AB (DO-5) 1/4" 28UNF-2A

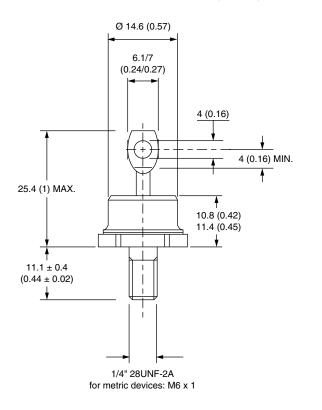
• M = stud base DO-203AB (DO-5) M6 x 1

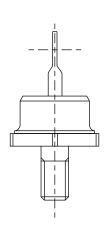
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95343		

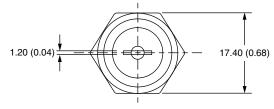


DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series

DIMENSIONS FOR 70HF(R) SERIES in millimeters (inches)







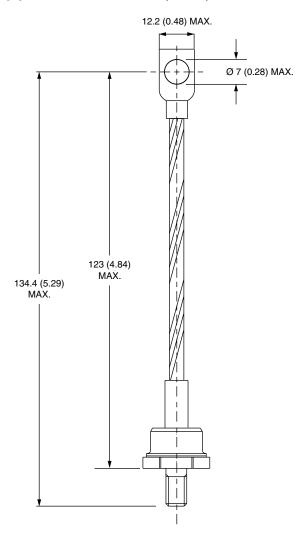
Outline Dimensions

Vishay Semiconductors

DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series



DIMENSIONS FOR 71HF(R) SERIES in millimeters (inches)





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